Common Collector Amplifier

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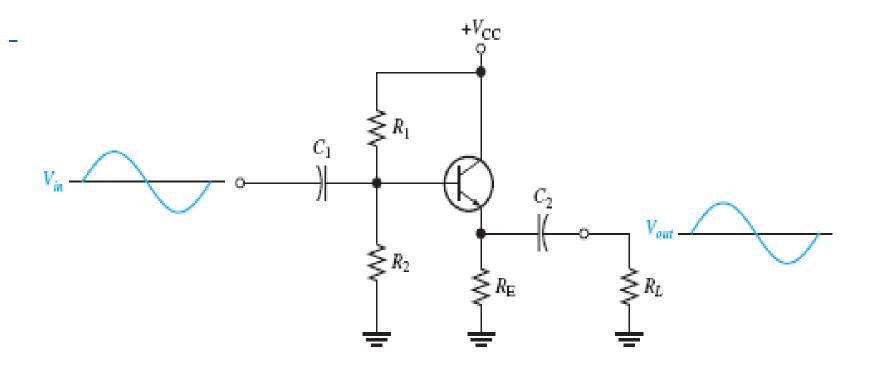
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THE COMMON-COLLECTOR (CC) AMPLIFIER

The common-collector (CC) amplifier is usually referred to as an emitter-follower (EF).

The input is applied to the base through a coupling capacitor, and the output is at the emitter.

The voltage gain of a CC amplifier is approximately 1, and its main advantages are its high input resistance and current gain.



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Voltage Gain

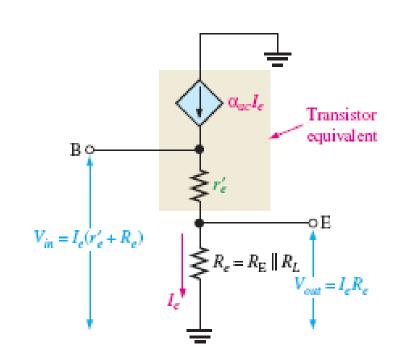
$$Av = V_{out} / V_{in}$$

$$V_{out} = I_e R_e$$

$$V_{in} = I_e(r'_e + R_e)$$

$$A_{\nu} = \frac{I_e R_e}{I_e (r'_e + R_e)}$$

$$A_v = \frac{R_e}{r'_e + R_e}$$



where Re is the parallel combination of $R_{\rm E}$ and $R_{\rm L}$. If there is no load, then Re $R_{\rm E}$.

Notice that the gain is always less than 1.

If $R_e \gg r'_e$, then a good approximation is

$$A_{\nu} \cong 1$$

Input Resistance

The emitter-follower is characterized by a high input resistance; this is what makes it a useful circuit. Because of the high input resistance, it can be used as a buffer to minimize loading effects when a circuit is driving a low-resistance load. The derivation of the input resistance, looking in at the base of the common-collector amplifier, is similar to that for the common-emitter amplifier. In a common-collector circuit, however, the emitter resistor is *never* bypassed because the output is taken across R_e , which is R_E in parallel with R_L .

$$R_{in(base)} = \frac{V_{in}}{I_{in}} = \frac{V_b}{I_b} = \frac{I_e(r_e' + R_e)}{I_b}$$

Since $I_e \cong I_c = \beta_{ac}I_b$,

$$R_{in(base)} \simeq \frac{\beta_{ac}I_b(r'_e + R_e)}{I_b}$$

The I_b terms cancel; therefore,

$$R_{in(base)} \cong \beta_{ac}(r'_e + R_e)$$

If $R_e \gg r_e'$, then the input resistance at the base is simplified to

$$R_{in(base)} \cong \beta_{ac}R_e$$

The bias resistors in Figure 6–25 appear in parallel with $R_{in(base)}$, looking from the input source; and just as in the common-emitter circuit, the total input resistance is

$$R_{in(tot)} = R_1 \| R_2 \| R_{in(base)}$$

Output Resistance

With the load removed, the output resistance, looking into the emitter of the emitter-follower, is approximated as follows:

$$R_{out} \cong \left(\frac{R_s}{\beta_{ac}}\right) | R_E$$

 R_s is the resistance of the input source. The derivation of Equation 6–14, found in "Derivations of Selected Equations" at www.pearsonhighered.com/floyd, is relatively involved and several assumptions have been made. The output resistance is very low, making the emitter-follower useful for driving low-resistance loads.

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Current Gain

$$A_i = \frac{I_e}{I_{in}}$$

where $I_{in} = V_{in}/R_{in(tot)}$.

Power Gain

The common-collector power gain is the product of the voltage gain and the current gain. For the emitter-follower, the power gain is approximately equal to the current gain because the voltage gain is approximately 1.

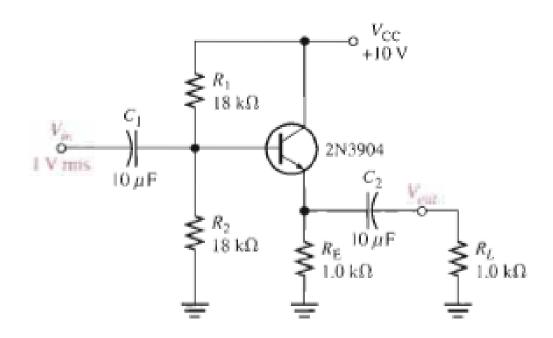
$$A_p = A_v A_i$$

Since $A_{\nu} \cong 1$, the power gain is

$$A_p \cong A_i$$

Example

Determine the total input resistance of the emitter-follower in Figure 6–27. Also find the voltage gain, current gain, and power gain in terms of power delivered to the load, R_L . Assume $\beta_{ac} = 175$ and that the capacitive reactances are negligible at the frequency of operation.



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The ac emitter resistance external to the transistor is

$$R_e = R_E \parallel R_L = 1.0 \text{ k}\Omega \parallel 1.0 \text{ k}\Omega = 500 \Omega$$

The approximate resistance, looking in at the base, is

$$R_{in(bose)} \cong \beta_{ac} R_e = (175)(500 \Omega) = 87.5 \text{ k}\Omega$$

The total input resistance is

$$R_{in(tot)} = R_1 \| R_2 \| R_{in(tot)se} = 18 \text{ k}\Omega \| 18 \text{ k}\Omega \| 87.5 \text{ k}\Omega = 8.16 \text{ k}\Omega$$

The voltage gain is $A_v \cong 1$. By using r'_e , you can determine a more precise value of A_v if necessary.

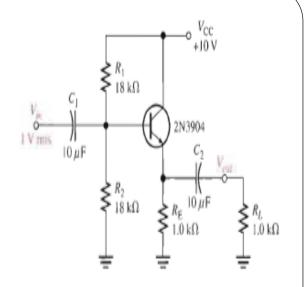
$$V_{\rm E} = \left(\frac{R_2}{R_1 + R_2}\right) V_{\rm CC} - V_{\rm BE} = (0.5)(10 \text{ V}) - 0.7 \text{ V} = 4.3 \text{ V}$$

Therefore,

$$I_{\rm E} = \frac{V_{\rm E}}{R_{\rm E}} \simeq \frac{4.3 \text{ V}}{1.0 \text{ k}\Omega} = 4.3 \text{ mA}$$

and

$$r_e' \simeq \frac{25 \text{ mV}}{I_E} = \frac{25 \text{ mV}}{4.3 \text{ mA}} = 5.8 \Omega$$



So,

$$A_{r} = \frac{R_{e}}{r_{e}' + R_{e}} = \frac{500 \,\Omega}{505.8 \,\Omega} = 0.989$$

The small difference in A_r as a result of considering r'_e is insignificant in most cases. The overall current gain is $A_i = I_e/I_{in}$. The calculations are as follows:

$$I_e = \frac{V_e}{R_e} = \frac{A_v V_b}{R_e} \cong \frac{1 \text{ V}}{500 \Omega} = 2 \text{ mA}$$

$$I_{in} = \frac{V_{in}}{R_{in(iot)}} = \frac{1 \text{ V}}{8.16 \text{ k}\Omega} = 123 \mu\text{A}$$

$$A_i = \frac{I_e}{I_{in}} = \frac{2 \text{ mA}}{123 \mu\text{A}} = 16.3$$

The overall power gain is

$$A_p \cong A_i = 16.3$$

Since $R_L = R_E$, one-half of the total power is dissipated in R_L . Therefore, in terms of power to the load, the power gain is one-half of the overall power gain.

$$A_{p(load)} = \frac{A_p}{2} = \frac{16.3}{2} = 8.15$$

